

FDMC7692 N-Channel Power Trench[®] MOSFET 30 V, 13.3 A, 8.5 m Ω

Features

- Max r_{DS(on)} = 8.5 mΩ at V_{GS} = 10 V, I_D = 13.3 A
- Max r_{DS(on)} = 11.5 mΩ at V_{GS} = 4.5 V, I_D = 10.6 A
- High performance technology for extremely low r_{DS(on)}
- Termination is Lead-free and RoHS Compliant

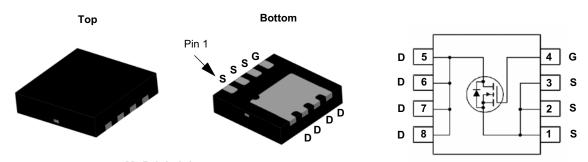


General Description

This N-Channel MOSFET is produced using Fairchild Semiconductor's advanced Power Trench[®] process that has been especially tailored to minimize the on-state resistance. This device is well suited for Power Management and load switching applications common in Notebook Computers and Portable Battery Packs.

Application

- DC DC Buck Converters
- Notebook battery power management
- Load switch in Notebook







Symbol	Parameter			Ratings	Units	
V _{DS}	Drain to Source Voltage			30	V	
V _{GS}	Gate to Source Voltage			±20	V	
ID	Drain Current -Continuous (Package limited)	T _C = 25 °C		16		
	-Continuous	T _A = 25 °C	(Note 1a)	13.3	Α	
	-Pulsed		40			
E _{AS}	Single Pulse Avalanche Energy		(Note 3)	58	mJ	
P _D	Power Dissipation	T _C = 25 °C		29	w	
	Power Dissipation	T _A = 25 °C	(Note 1a)	2.3	V	
T _J , T _{STG}	Operating and Storage Junction Temperature R	ange		-55 to +150	°C	

Thermal Characteristics

$R_{ ext{ heta}JC}$	Thermal Resistance, Junction to Case	4.3	°C/W
$R_{ ext{ heta}JA}$	Thermal Resistance, Junction to Ambient (Note 1a)	53	C/VV

Package Marking and Ordering Information

Device Marking	vice Marking Device		Package Reel Size		Quantity	
FDMC7692	FDMC7692	MLP 3.3x3.3	13 " 12 mm		3000 units	

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	Drain to Course Drashalar Villan	$1 - 250 \dots A M = 0 M$	00		1	
BV _{DSS}	Drain to Source Breakdown Voltage	I _D = 250 μA, V _{GS} = 0 V	30			V
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	I_D = 250 μ A, referenced to 25 °C		16		mV/
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 24 V, V _{GS} = 0 V T _J = 125 °C			1 250	μ4
I _{GSS}	Gate to Source Leakage Current	T _J = 125 °C V _{GS} = 20 V, V _{DS} = 0 V			100	nA
On Chara	acteristics					
V _{GS(th)}	Gate to Source Threshold Voltage	V _{GS} = V _{DS} , I _D = 250 μA	1.2	1.9	3.0	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = 250 \ \mu$ A, referenced to 25 °C		-6		mV/
		V _{GS} = 10 V, I _D = 13.3 A		7.2	8.5	
r _{DS(on)}	Static Drain to Source On Resistance	V _{GS} = 4.5 V, I _D = 10.6 A		9.5	11.5	mg
20(01)		V _{GS} = 10 V, I _D = 13.3 A, T _J = 125 °C		9.5	12.0	
9 _{FS}	Forward Transconductance	$V_{DD} = 5 V, I_D = 13.3 A$		60		S
	Characteristics					
C _{iss}	Input Capacitance			1260	1680	pF
C _{oss}	Output Capacitance	— V _{DS} = 15 V, V _{GS} = 0 V,		480	635	pF
	Reverse Transfer Capacitance	f = 1 MHz		65	100	pF
C _{rss}	Gate Resistance			0.9	2.4	Ω
R _g				0.5	2.4	52
Switchin	g Characteristics	-	T		1	1
t _{d(on)}	Turn-On Delay Time			9	18	ns
t _r	Rise Time	V _{DD} = 15 V, I _D = 13.3 A,		4	10	ns
t _{d(off)}	Turn-Off Delay Time	V _{GS} = 10 V, R _{GEN} = 6 Ω		21	33	ns
t _f	Fall Time			3	10	ns
Q _{g(TOT)}	Total Gate Charge	$V_{GS} = 0 V$ to 10 V		21	29	nC
	Total Gate Charge	V_{GS} = 0 V to 4.5 V V_{DD} = 15 V		10	14	nC
Q _{gs}	Total Gate Charge	I _D = 13.3 A		5		nC
Q _{gd}	Gate to Drain "Miller" Charge			3		nC
Drain-So	ource Diode Characteristics					
M		V _{GS} = 0 V, I _S = 13.3 A (Note 2)		0.86	1.2	v
V _{SD}	Source to Drain Diode Forward Voltage	V _{GS} = 0 V, I _S = 1.9 A (Note 2)		0.75	1.2	v
t _{rr}	Reverse Recovery Time	I _E = 13.3 A, di/dt = 100 A/μs		24	38	ns
Q _{rr}	Reverse Recovery Charge	$F = 10.5 \text{ A}, \text{ div}\text{dt} = 100 \text{ A}/\mu\text{s}$		7	14	nC
NOTES: 1. R _{0JA} is detern the user's bo	mined with the device mounted on a 1 in ² pad 2 oz copper p vard design. a. 53 °C/W when mounte a 1 in ² pad of 2 oz co	ed on b.125 °C/	guaranteed b W when mou Im pad of 2 (inted on	e R _{θCA} is de	termine
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Test Conditions

Min

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Electrical Characteristics T_J = 25 °C unless otherwise noted

Parameter

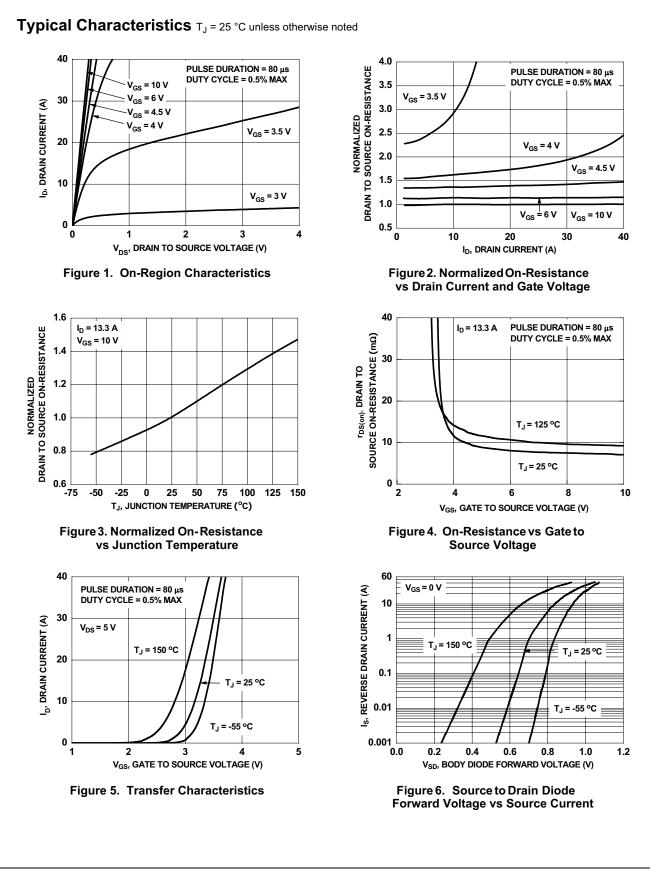
Symbol

Units

Max

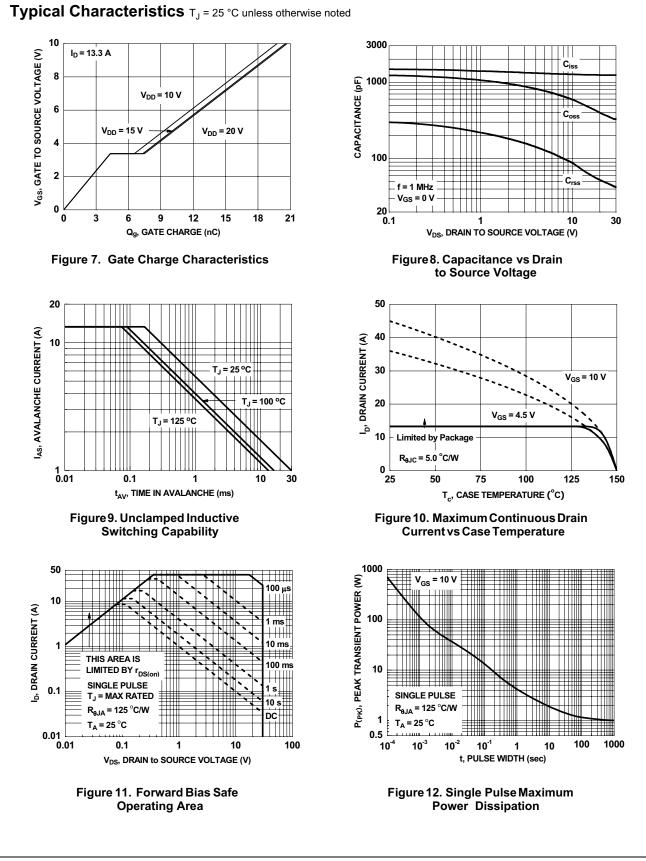
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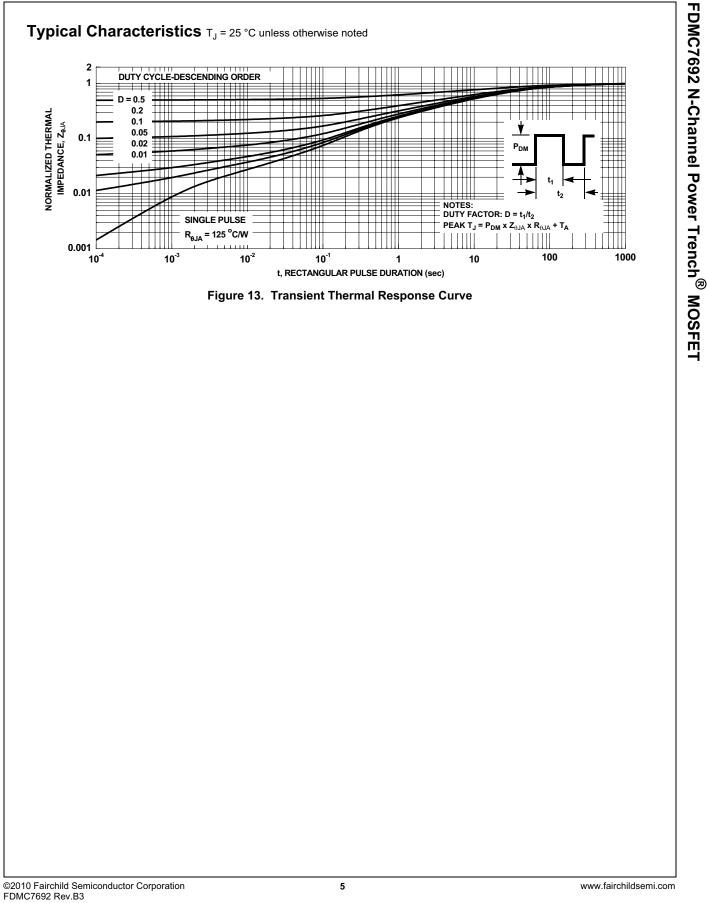


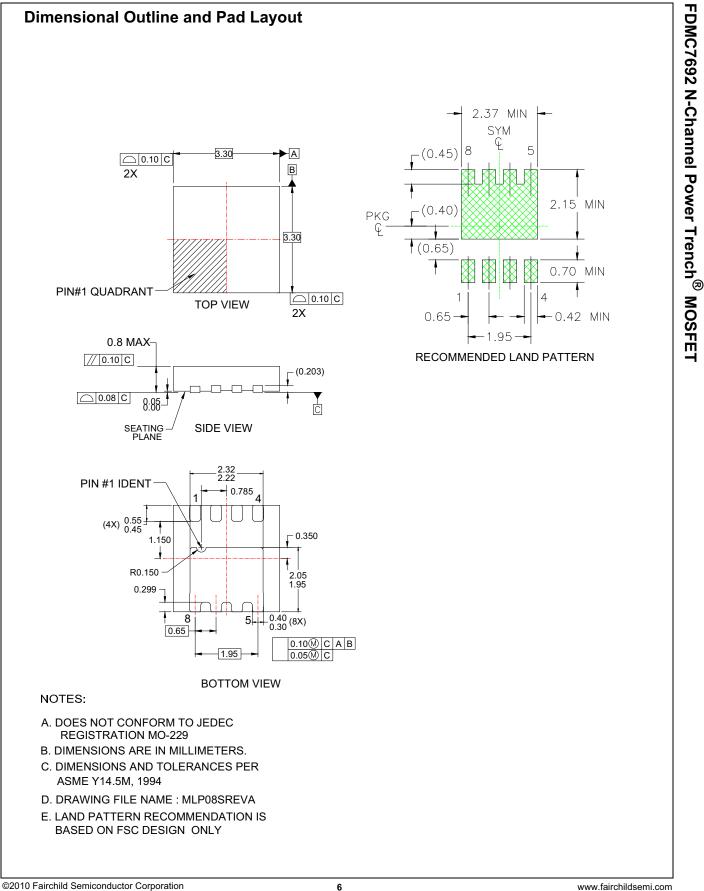
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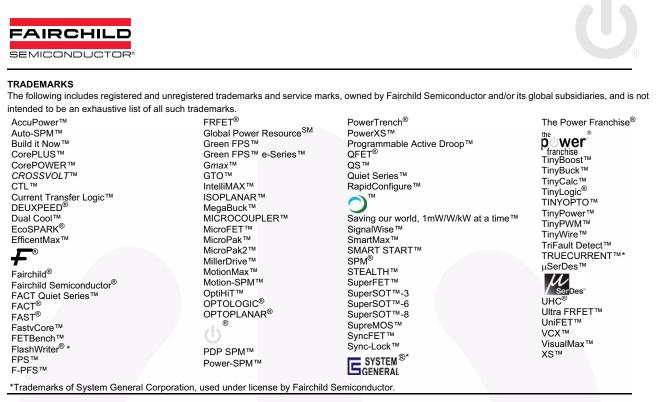


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